

Description

The AU1204S2 is a TVS array, utilizing leading monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive portable electronics. The AU1204S2 complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 6-lead SOT23-6 lead-free package. The leads are finished with lead-free matte tin. Each device will protect up to four lines.

Features

- Protects up to 4 lines
- Low leakage: nA level
- Low clamping voltage
- Excellent surge protection (200W at 8/20 μs)
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: $\pm 30\text{kV}$
Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 9A (8/20 μs)
- RoHS Compliant

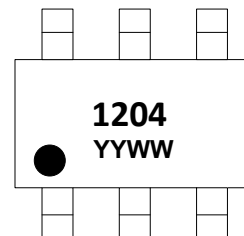
Mechanical Characteristics

- Package: SOT23-6
- Lead Finish: Matte Tin
- Case Material: “Green” Molding Compound
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

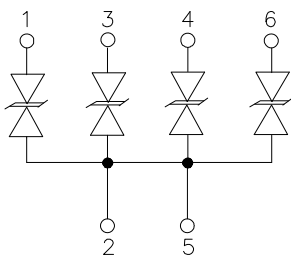
- Audio Players
- Peripherals
- Portable Instrumentation
- Desktops PC and Servers
- Microprocessor Based Equipment
- Cell Phone Handsets and Accessories
- Notebook, Laptop, and Palmtop Computers

Marking Information

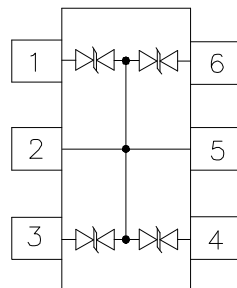


1204 = Device Marking Code
 YYWW = Date Code
 Dot denotes pin 1

Dimensions and Pin Configuration



Circuit Schematic



Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size
AU1204S2	3000/Tape & Reel	7 inch

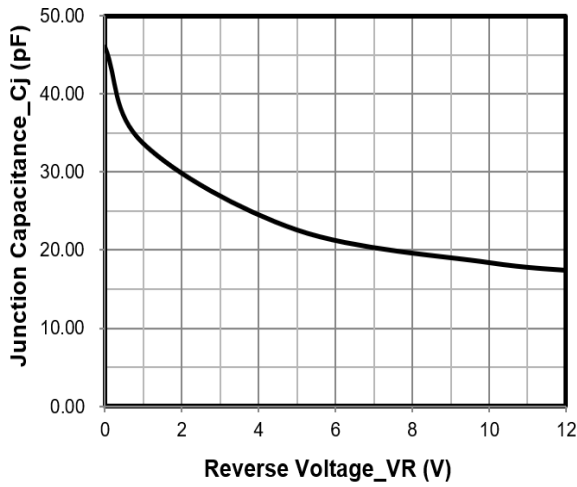
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	200	W
Peak Pulse Current (8/20μs)	I _{PP}	9	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

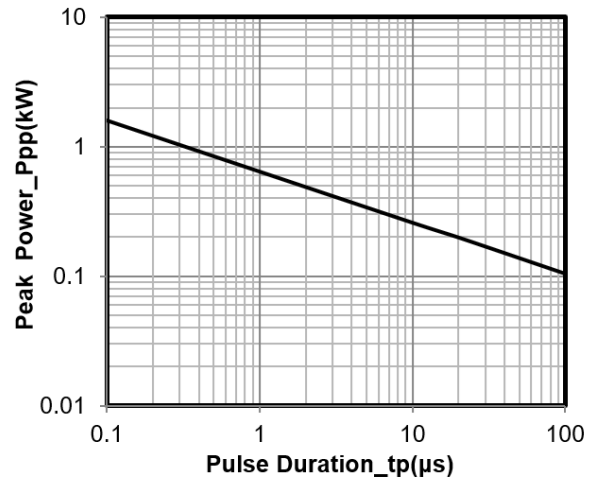
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			12	V	
Breakdown Voltage	V _{BR}	13.5			V	I _T = 1mA
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 12V
Clamping Voltage	V _C			16	V	I _{PP} = 1A
Clamping Voltage	V _C			22.5	V	I _{PP} = 9A
Junction Capacitance	C _J		46		pF	V _R = 0V, f = 1MHz, any I/O pin to ground

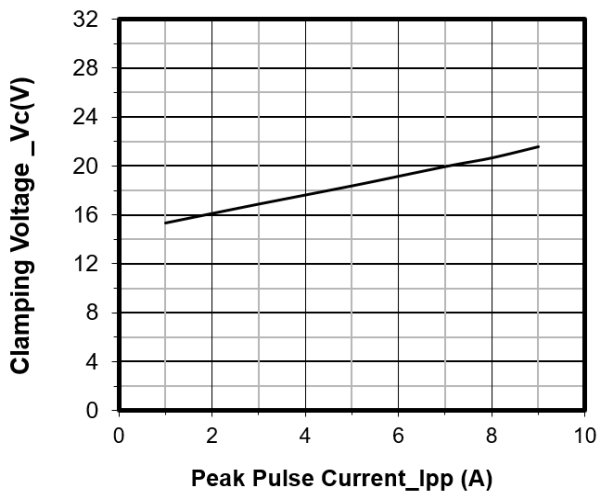
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



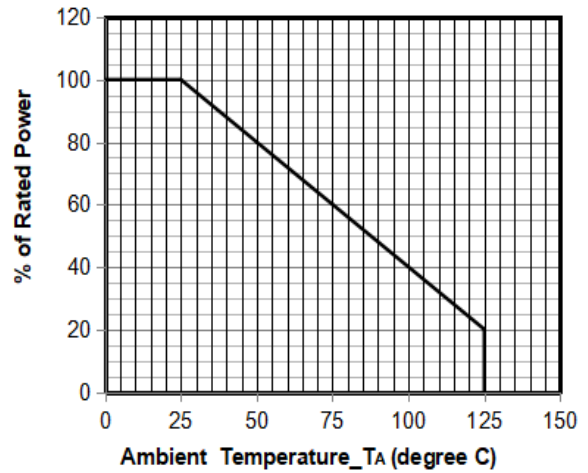
Junction Capacitance vs. Reverse Voltage



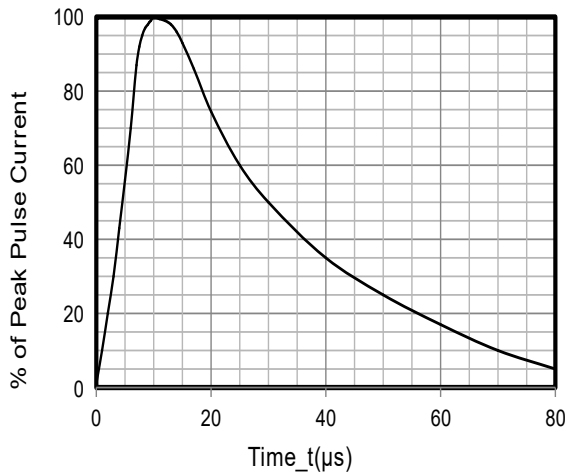
Peak Pulse Power vs. Pulse Time



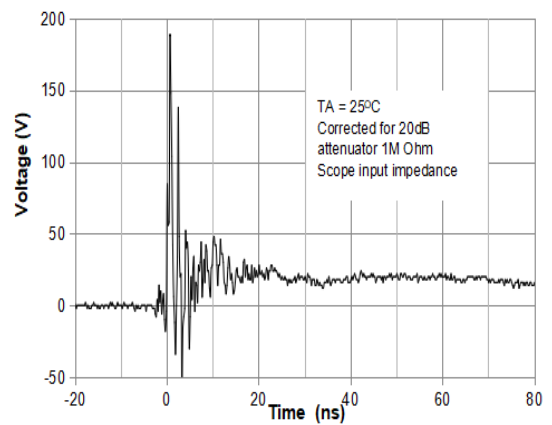
Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20\mu\text{s}$)



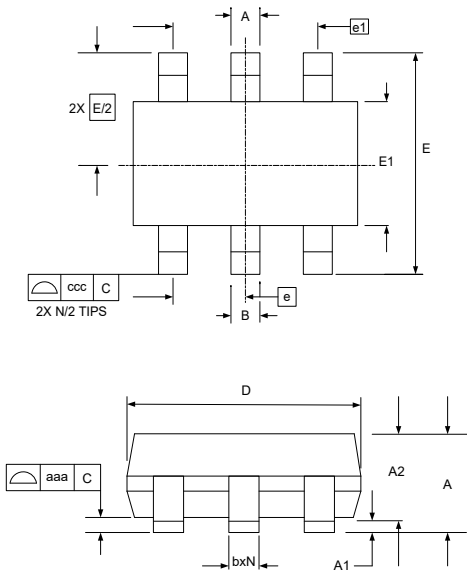
Power Derating Curve



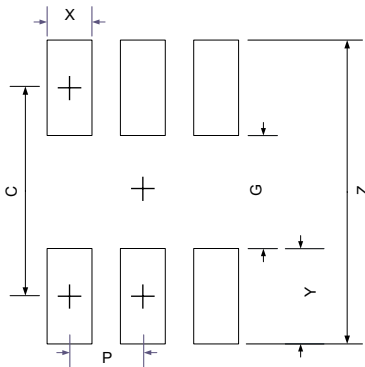
8 X 20 μs Pulse Waveform



ESD Clamping Voltage
8 kV Contact per IEC61000-4-2

SOT23-6 Package Outline Drawing


SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90		1.45	0.035		0.057
A1	0.00		0.15	0.000		0.006
A2	0.90	1.15	1.30	0.035	0.045	0.051
b	0.25		0.50	0.010		0.020
c	0.08		0.22	0.003		0.009
D	2.80	2.90	3.10	0.110	0.114	0.122
E1	1.50	1.60	1.75	0.060	0.063	0.069
E	2.80 BSC			0.110 BSC		
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
N	6			6		
aaa	0.10			0.004		
ccc	0.20			0.008		

Suggested Land Pattern


SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	2.50	0.098
G	1.40	0.055
P	0.95	0.037
X	0.60	0.024
Y	1.10	0.043
Z	3.60	0.141

Contact Information

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